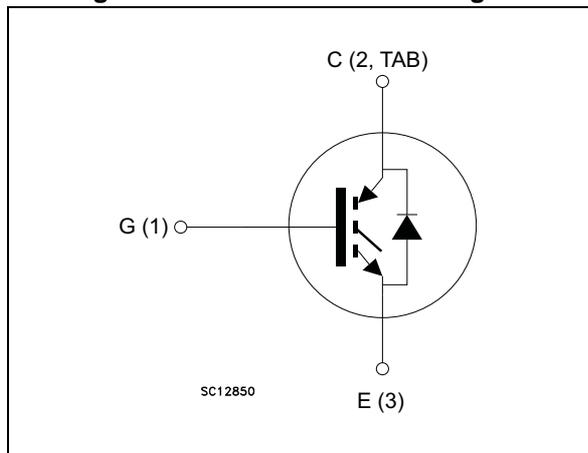


Figure 1. Internal schematic diagram



### Features

- High speed switching
- Tight parameters distribution
- Safe paralleling
- Low thermal resistance
- Short-circuit rated
- Ultrafast soft recovery antiparallel diode

### Applications

- Motor control
- UPS, PFC

### Description

This device is an IGBT developed using an advanced proprietary trench gate and field stop structure. This IGBT series offers the optimum compromise between conduction and switching losses, maximizing the efficiency of very high frequency converters. Furthermore, a positive  $V_{CE(sat)}$  temperature coefficient and very tight parameter distribution result in easier paralleling operation.

Table 1. Device summary

| Order codes | Marking  | Packages           | Packaging     |
|-------------|----------|--------------------|---------------|
| STGB7H60DF  | GB7H60DF | D <sup>2</sup> PAK | Tape and reel |
| STGF7H60DF  | GF7H60DF | TO-220FP           | Tube          |
| STGP7H60DF  | GP7H60DF | TO-220             | Tube          |

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# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

| Symbol         | Parameter   | TO-220<br>D <sup>2</sup> PAK | TO-220FP          | Unit |
|----------------|---|------------------------------|-------------------|------|
| $V_{CES}$      | Collector-emitter voltage ( $V_{GE} = 0$ )  | 600                          |                   | V    |
| $I_C$          | Continuous collector current at $T_C = 25\text{ °C}$  | 14                           | 14 <sup>(1)</sup> | A    |
|                | Continuous collector current at $T_C = 100\text{ °C}$   | 7                            | 7 <sup>(1)</sup>  |      |
| $I_{CP}^{(2)}$ | Pulsed collector current  | 28                           | 28 <sup>(1)</sup> | A    |
| $V_{GE}$       | Gate-emitter voltage  | ±20                          |                   | V    |
| $I_F$          | Continuous forward current $T_C = 25\text{ °C}$   | 14                           | 14 <sup>(1)</sup> | A    |
|                | Continuous forward current at $T_C = 100\text{ °C}$   | 7                            | 7 <sup>(1)</sup>  |      |
| $I_{FP}^{(2)}$ | Pulsed forward current  | 28                           | 28 <sup>(1)</sup> | A    |
| $V_{ISO}$      | Insulation withstand voltage (RMS) from all three leads to external heat sink ( $t = 1\text{ s}$ , $T_C = 25\text{ °C}$ ) |                              | 2500              | V    |
| $P_{TOT}$      | Total dissipation at $T_C = 25\text{ °C}$   | 88                           | 24                | W    |
| $T_{STG}$      | Storage temperature range   | - 55 to 150                  |                   | °C   |
| $T_J$          | Operating junction temperature  | - 55 to 175                  |                   |      |

1. Limited by maximum junction temperature.
2. Pulse width limited by maximum junction temperature.

**Table 3. Thermal data**

| Symbol     | Parameter                              | TO-220<br>D <sup>2</sup> PAK | TO-220FP | Unit |
|------------|--|------------------------------|----------|------|
| $R_{thJC}$ | Thermal resistance junction-case IGBT  | 1.7                          | 6.2      | °C/W |
| $R_{thJC}$ | Thermal resistance junction-case diode | 2.8                          | 6.25     | °C/W |
| $R_{thJA}$ | Thermal resistance junction-ambient    | 62.5                         |          | °C/W |

## 2 Electrical characteristics

$T_J = 25\text{ °C}$  unless otherwise specified.

**Table 4. Static**

| Symbol        | Parameter   | Test conditions   | Min. | Typ. | Max. | Unit          |
|---------------|---|---|------|------|------|---------------|
| $V_{(BR)CES}$ | Collector-emitter breakdown voltage ( $V_{GE} = 0\text{ V}$ ) | $I_C = 2\text{ mA}$   | 600  |      |      | V             |
| $V_{CE(sat)}$ | Collector-emitter saturation voltage                          | $V_{GE} = 15\text{ V}, I_C = 7\text{ A}$                          |      | 1.5  | 1.95 | V             |
|               |   | $V_{GE} = 15\text{ V}, I_C = 7\text{ A}$<br>$T_J = 125\text{ °C}$ |      | 1.6  |      |               |
|               |   | $V_{GE} = 15\text{ V}, I_C = 7\text{ A}$<br>$T_J = 175\text{ °C}$ |      | 1.7  |      |               |
| $V_{GE(th)}$  | Gate threshold voltage  | $V_{CE} = V_{GE}, I_C = 250\text{ }\mu\text{A}$                   | 4.8  | 6.2  | 6.9  | V             |
| $I_{CES}$     | Collector cut-off current ( $V_{GE} = 0\text{ V}$ )           | $V_{CE} = 600\text{ V}$   |      |      | 25   | $\mu\text{A}$ |
| $I_{GES}$     | Gate-emitter leakage current ( $V_{CE} = 0\text{ V}$ )        | $V_{GE} = \pm 20\text{ V}$  |      |      | 250  | nA            |

**Table 5. Dynamic**

| Symbol    | Parameter                    | Test conditions  | Min. | Typ. | Max. | Unit |
|-----------|------------------------------|--|------|------|------|------|
| $C_{ies}$ | Input capacitance            | $V_{CE} = 25\text{ V}, f = 1\text{ MHz},$<br>$V_{GE} = 0\text{ V}$   | -    | 1050 | -    | pF   |
| $C_{oes}$ | Output capacitance           |  | -    | 51   | -    |      |
| $C_{res}$ | Reverse transfer capacitance |  | -    | 23   | -    |      |
| $Q_g$     | Total gate charge            | $V_{CC} = 480\text{ V}, I_C = 7\text{ A},$<br>$V_{GE} = 15\text{ V}$ | -    | 46   | -    | nC   |
| $Q_{ge}$  | Gate-emitter charge          |  | -    | 7    | -    |      |
| $Q_{gc}$  | Gate-collector charge        |  | -    | 21   | -    |      |

Table 6. Switching characteristics (inductive load)

| Symbol         | Parameter                    | Test conditions  | Min. | Typ. | Max. | Unit       |
|----------------|------------------------------|--|------|------|------|------------|
| $t_{d(on)}$    | Turn-on delay time           | $V_{CE} = 400\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 47\ \Omega$ , $V_{GE} = 15\text{ V}$                                      | -    | 30   | -    | ns         |
| $t_r$          | Current rise time            |  | -    | 12.2 | -    | ns         |
| $(di/dt)_{on}$ | Turn-on current slope        |  | -    | 459  | -    | A/ $\mu$ s |
| $t_{d(on)}$    | Turn-on delay time           | $V_{CE} = 400\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 47\ \Omega$ , $V_{GE} = 15\text{ V}$<br>$T_J = 175\text{ }^\circ\text{C}$ | -    | 30   | -    | ns         |
| $t_r$          | Current rise time            |  | -    | 12.8 | -    | ns         |
| $(di/dt)_{on}$ | Turn-on current slope        |  | -    | 440  | -    | A/ $\mu$ s |
| $t_{r(Voff)}$  | Off voltage rise time        | $V_{CE} = 400\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 47\ \Omega$ , $V_{GE} = 15\text{ V}$                                      | -    | 24   | -    | ns         |
| $t_{d(off)}$   | Turn-off delay time          |  | -    | 160  | -    |            |
| $t_f$          | Current fall time            |  | -    | 69   | -    |            |
| $t_{r(Voff)}$  | Off voltage rise time        | $V_{CE} = 400\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 47\ \Omega$ , $V_{GE} = 15\text{ V}$<br>$T_J = 175\text{ }^\circ\text{C}$ | -    | 31   | -    | ns         |
| $t_{d(off)}$   | Turn-off delay time          |  | -    | 164  | -    |            |
| $t_f$          | Current fall time            |  | -    | 99   | -    |            |
| $t_{sc}$       | Short-circuit withstand time | $V_{CC} \leq 360\text{ V}$ , $V_{GE} = 15\text{ V}$ ,<br>$R_G = 47\ \Omega$  | -    | 5    | -    | $\mu$ s    |

Table 7. Switching energy (inductive load)

| Symbol          | Parameter                 | Test conditions  | Min. | Typ. | Max. | Unit    |
|-----------------|---------------------------|--|------|------|------|---------|
| $E_{on}^{(1)}$  | Turn-on switching losses  | $V_{CE} = 400\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 47\ \Omega$ , $V_{GE} = 15\text{ V}$                                      | -    | 99   | -    | $\mu$ J |
| $E_{off}^{(2)}$ | Turn-off switching losses |  | -    | 100  | -    |         |
| $E_{ts}$        | Total switching losses    |  | -    | 199  | -    |         |
| $E_{on}^{(1)}$  | Turn-on switching losses  | $V_{CE} = 400\text{ V}$ , $I_C = 7\text{ A}$ ,<br>$R_G = 47\ \Omega$ , $V_{GE} = 15\text{ V}$<br>$T_J = 175\text{ }^\circ\text{C}$ | -    | 202  | -    | $\mu$ J |
| $E_{off}^{(2)}$ | Turn-off switching losses |  | -    | 149  | -    |         |
| $E_{ts}$        | Total switching losses    |  | -    | 351  | -    |         |

1. Energy losses include reverse recovery of the diode.
2. Turn-off losses include also the tail of the collector current.

Table 8. Collector-emitter diode

| Symbol    | Parameter                | Test conditions   | Min. | Typ. | Max. | Unit |
|-----------|--------------------------|---|------|------|------|------|
| $V_F$     | Forward on-voltage       | $I_F = 7\text{ A}$  | -    | 1.5  | 2.1  | V    |
|           |                          | $I_F = 7\text{ A}, T_J = 175\text{ °C}$   |      | 1.15 |      |      |
| $t_{rr}$  | Reverse recovery time    | $V_{CC} = 400\text{ V}; I_F = 7\text{ A};$<br>$di_F/dt = 100\text{ A}/\mu\text{s}$                          | -    | 136  |      | ns   |
| $Q_{rr}$  | Reverse recovery charge  |   | -    | 104  |      | nC   |
| $I_{rrm}$ | Reverse recovery current |   | -    | 2.25 |      | A    |
| $t_{rr}$  | Reverse recovery time    | $V_{CC} = 400\text{ V}; I_F = 7\text{ A};$<br>$di_F/dt = 100\text{ A}/\mu\text{s}$<br>$T_J = 175\text{ °C}$ | -    | 154  |      | ns   |
| $Q_{rr}$  | Reverse recovery charge  |   | -    | 388  |      | nC   |
| $I_{rrm}$ | Reverse recovery current |   | -    | 4.6  |      | A    |

## 2.1 Electrical characteristics (curves)

Figure 2. Power dissipation vs. case temperature for D<sup>2</sup>PAK and TO-220

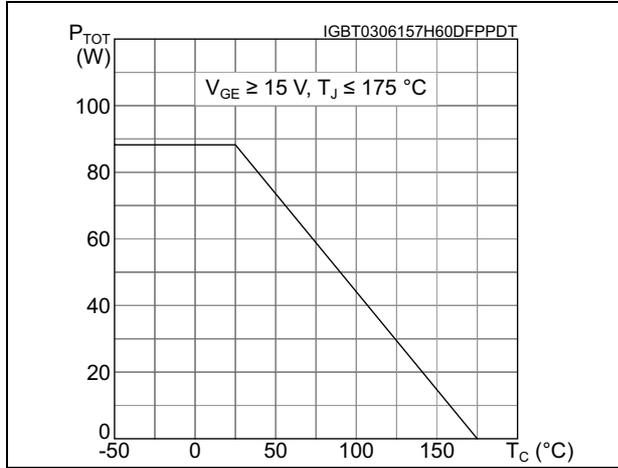


Figure 3. Collector current vs. case temperature for D<sup>2</sup>PAK and TO-220

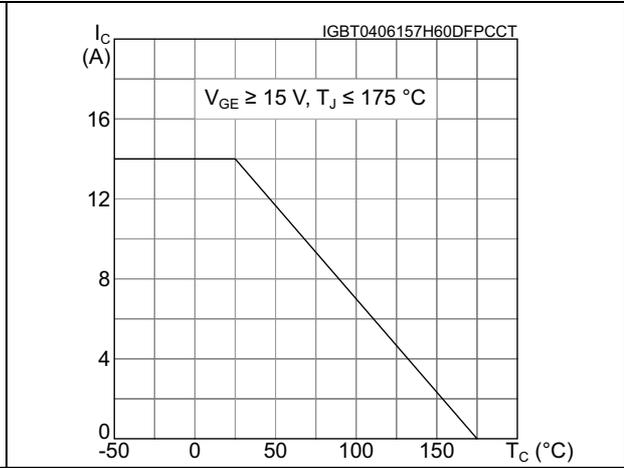


Figure 4. Power dissipation vs. case temperature for TO-220FP

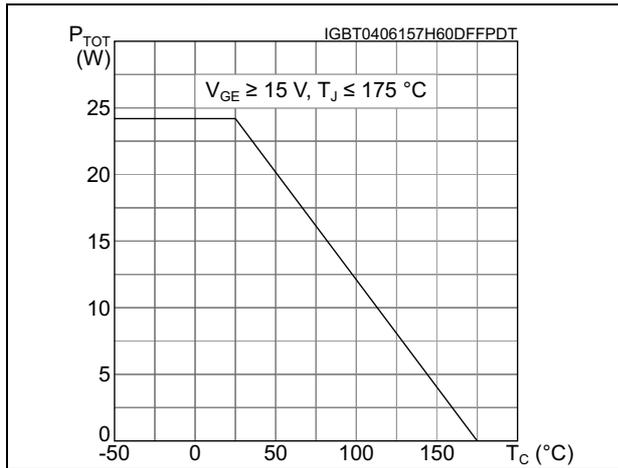


Figure 5. Collector current vs. case temperature for TO-220FP

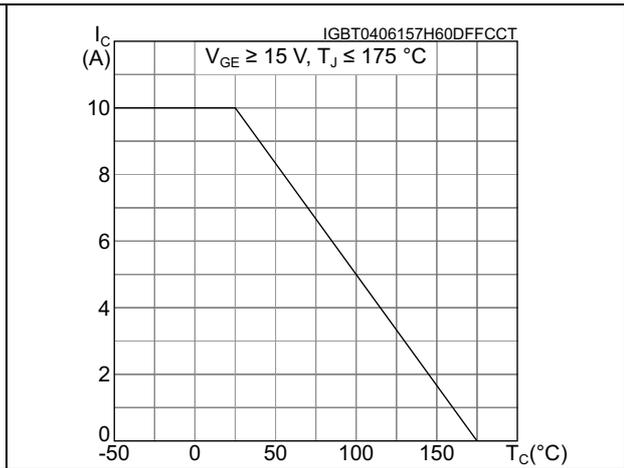


Figure 6. Output characteristics ( $T_J = 25$  °C)

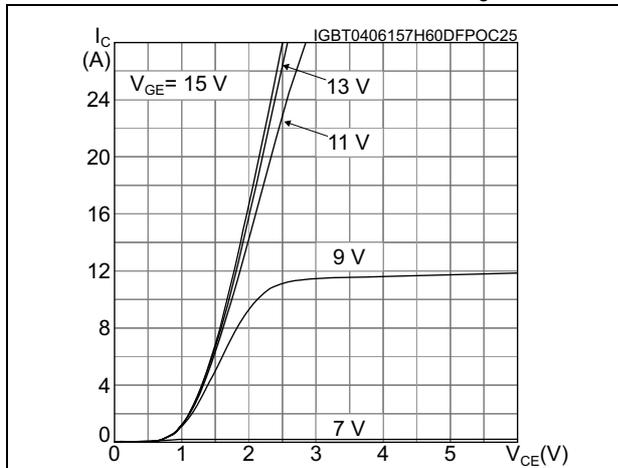


Figure 7. Output characteristics ( $T_J = 175$  °C)

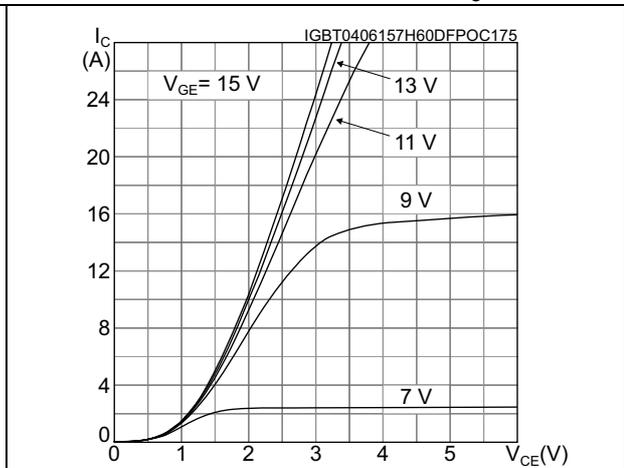


Figure 8.  $V_{CE(sat)}$  vs. junction temperature

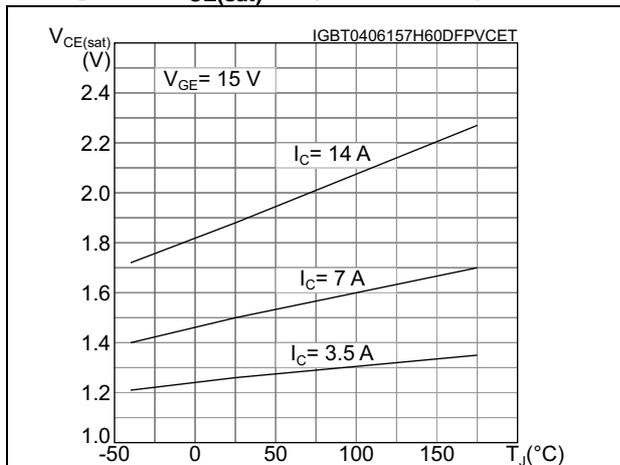


Figure 9.  $V_{CE(sat)}$  vs. collector current

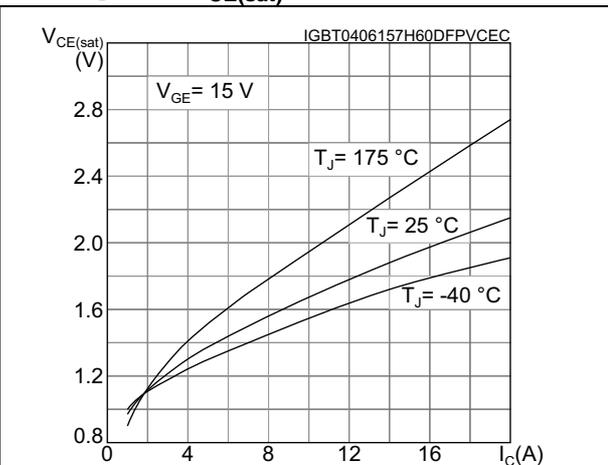


Figure 10. Collector current vs. switching frequency for D<sup>2</sup>PAK and TO-220

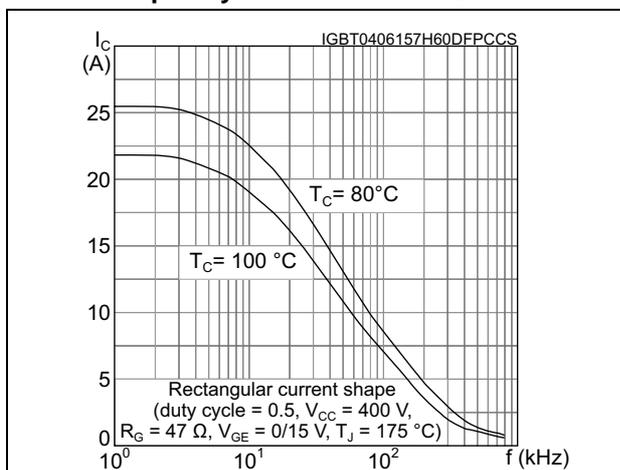


Figure 11. Collector current vs. switching frequency for TO-220FP

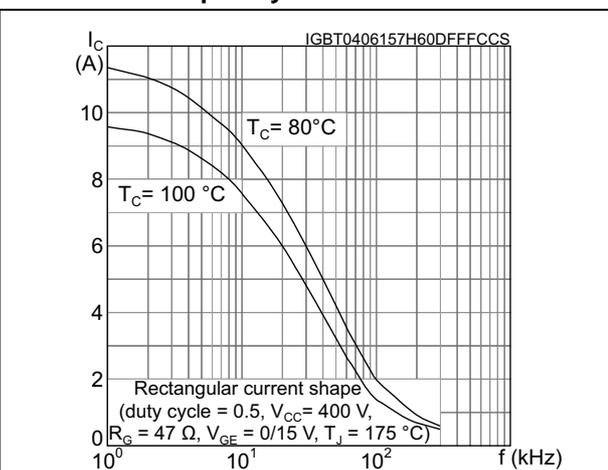


Figure 12. Forward bias safe operating area for D<sup>2</sup>PAK and TO-220

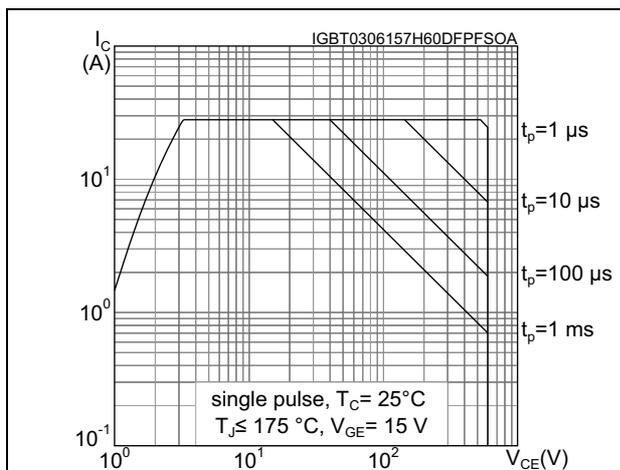


Figure 13. Forward bias safe operating area for TO-220FP

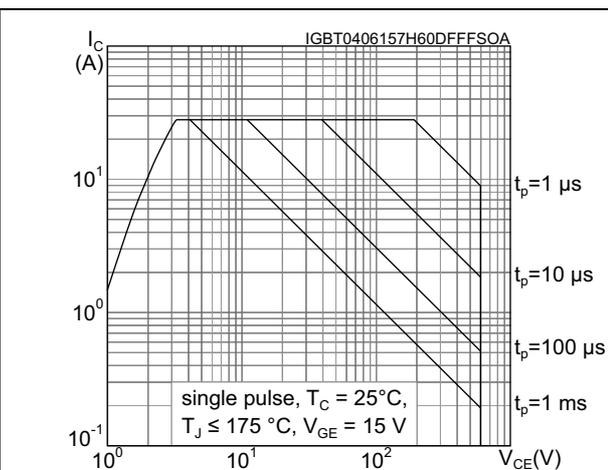


Figure 14. Transfer characteristics

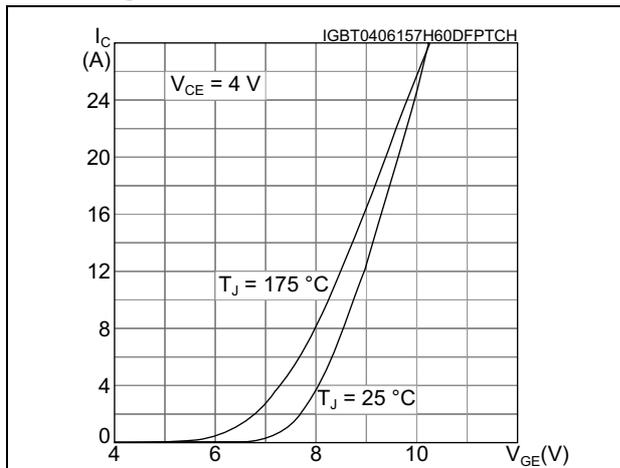


Figure 15. Diode VF vs. forward current

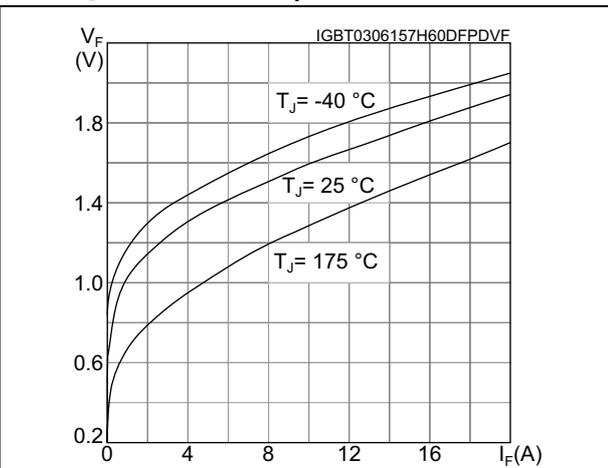


Figure 16. Normalized VGE(th) vs. junction temperature

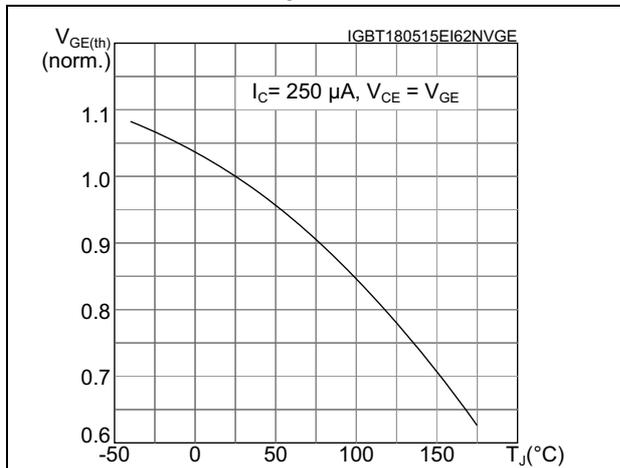


Figure 17. Normalized VBR(CES) vs. junction temperature

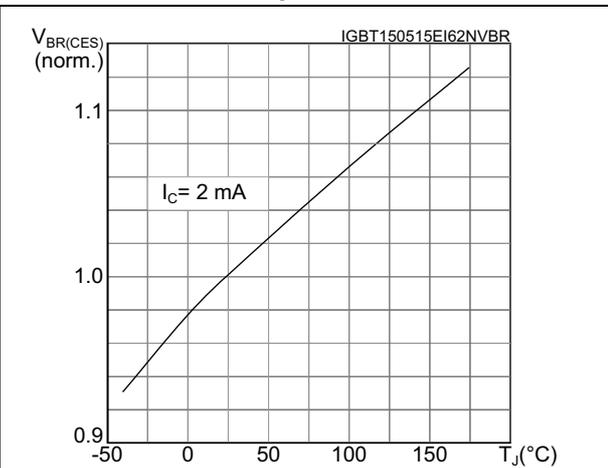


Figure 18. Capacitance variation

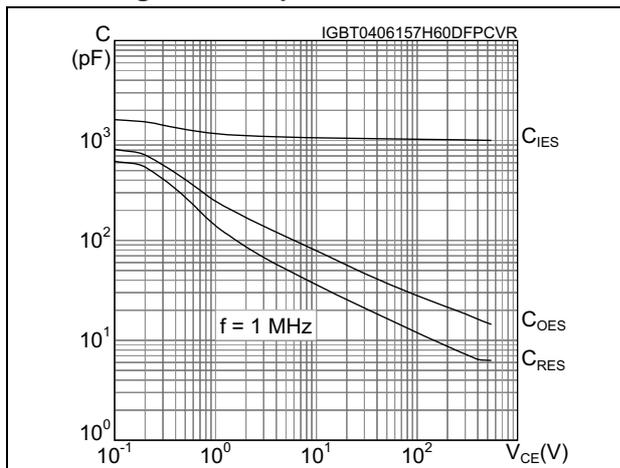


Figure 19. Gate charge vs. gate-emitter voltage

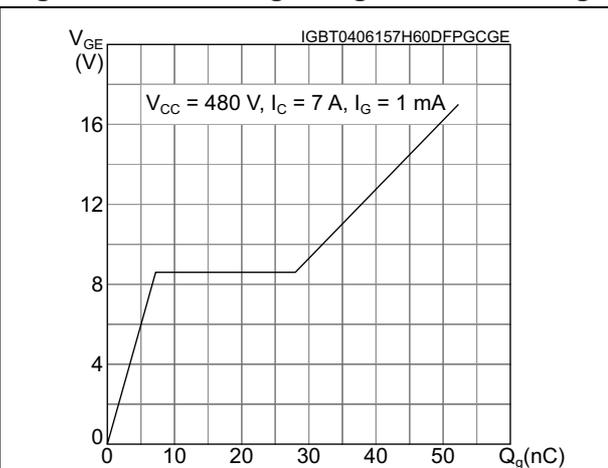


Figure 20. Switching loss vs. collector current

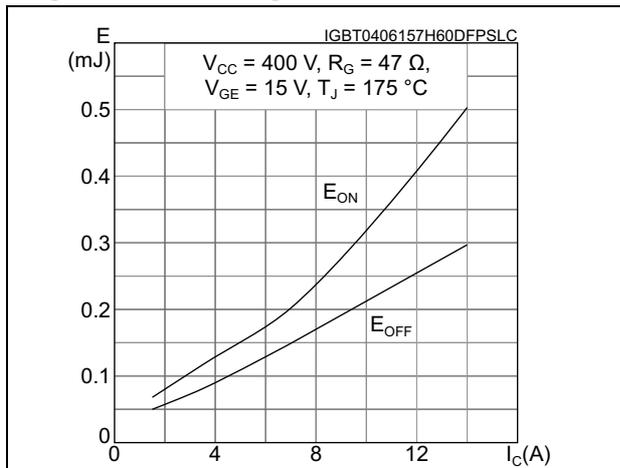


Figure 21. Switching loss vs. gate resistance

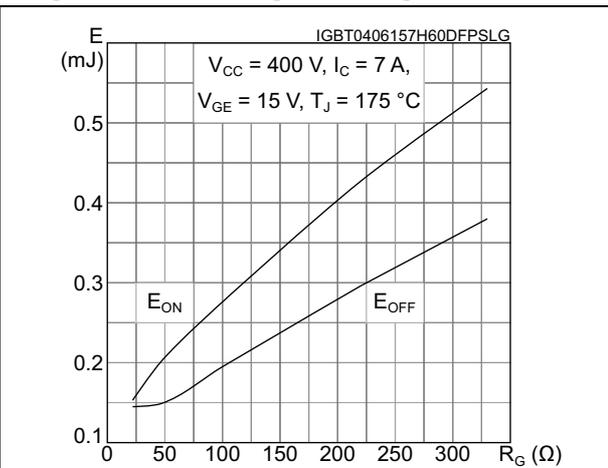


Figure 22. Switching loss vs. temperature

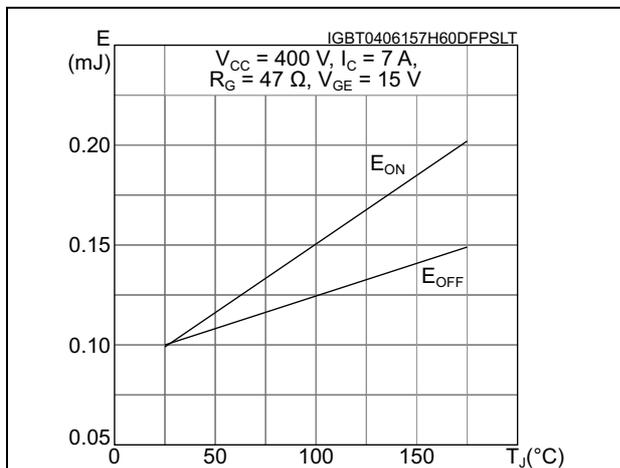


Figure 23. Switching loss vs. collector-emitter voltage

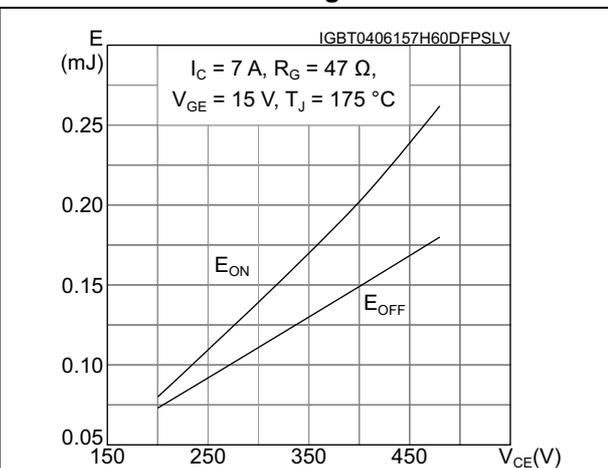


Figure 24. Short circuit time and current vs. Vge

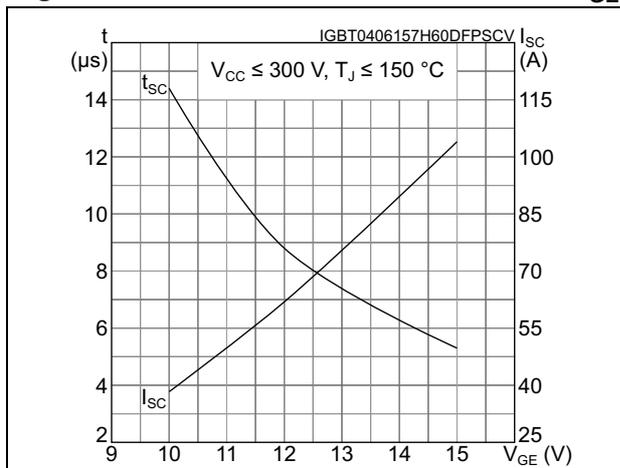


Figure 25. Switching times vs. collector current

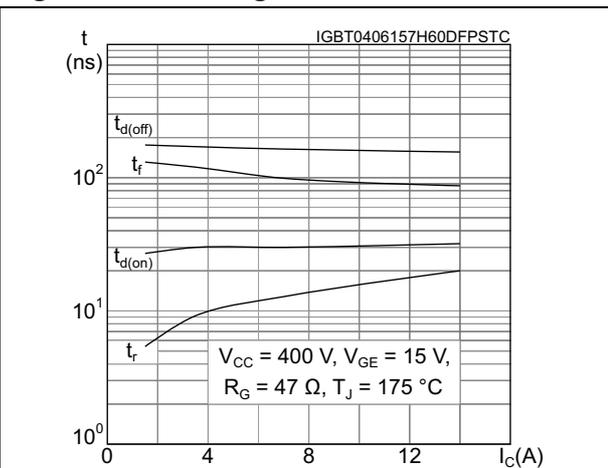


Figure 26. Switching times vs. gate resistance

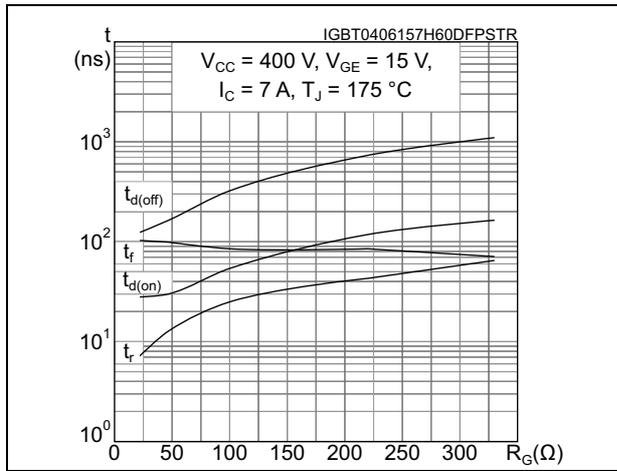


Figure 27. Reverse recovery current vs. diode current slope

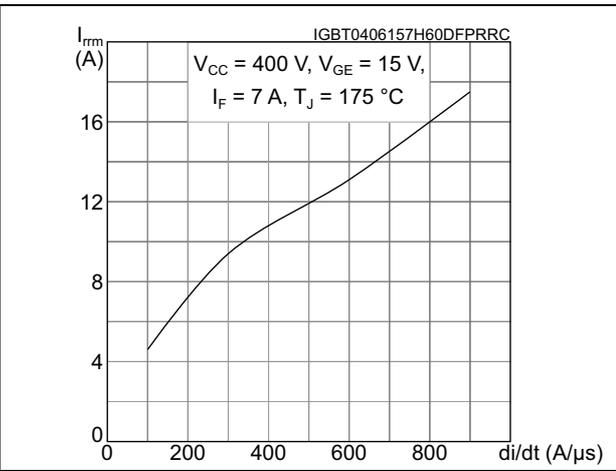


Figure 28. Reverse recovery time vs. diode current slope

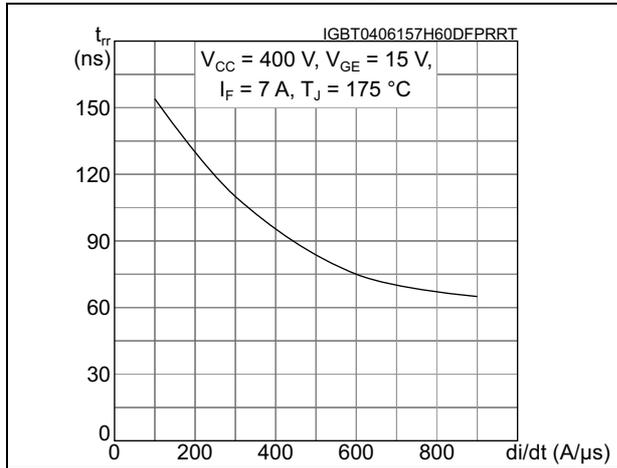


Figure 29. Reverse recovery charge vs. diode current slope

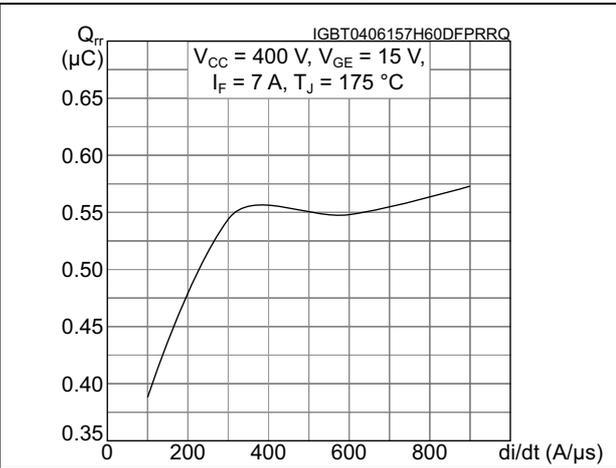


Figure 30. Reverse recovery energy vs. diode current slope

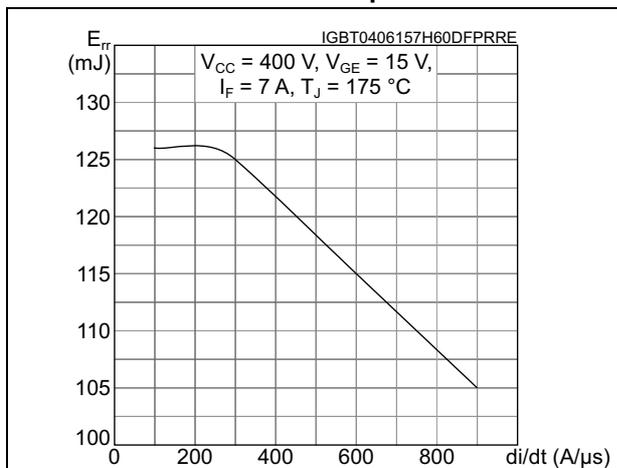


Figure 31. Thermal impedance for D<sup>2</sup>PAK and TO-220 IGBT

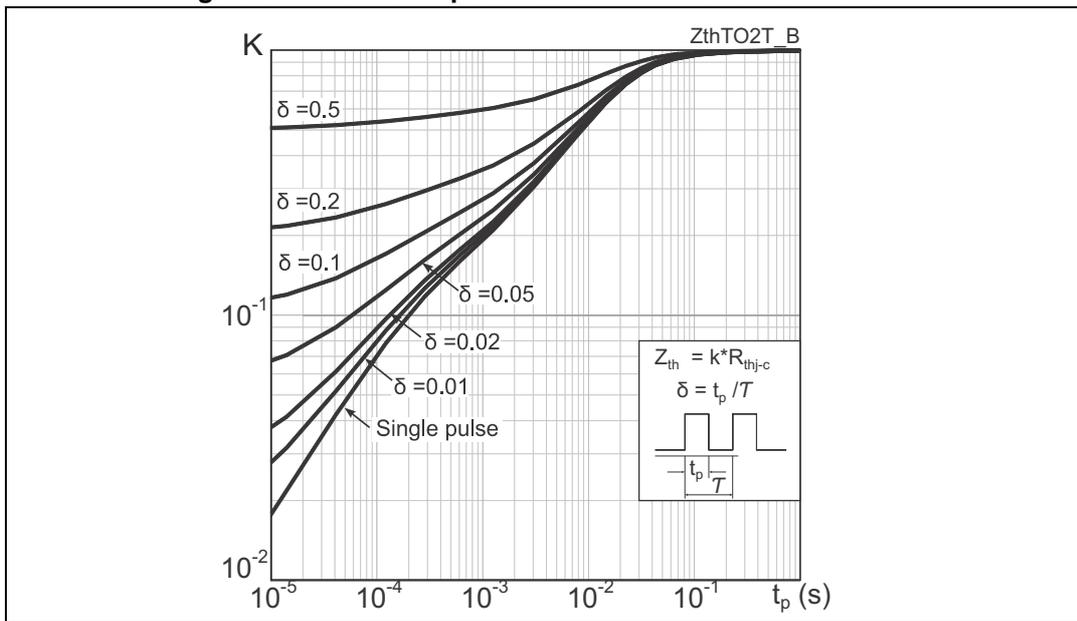


Figure 32. Thermal impedance for D<sup>2</sup>PAK and TO-220 diode

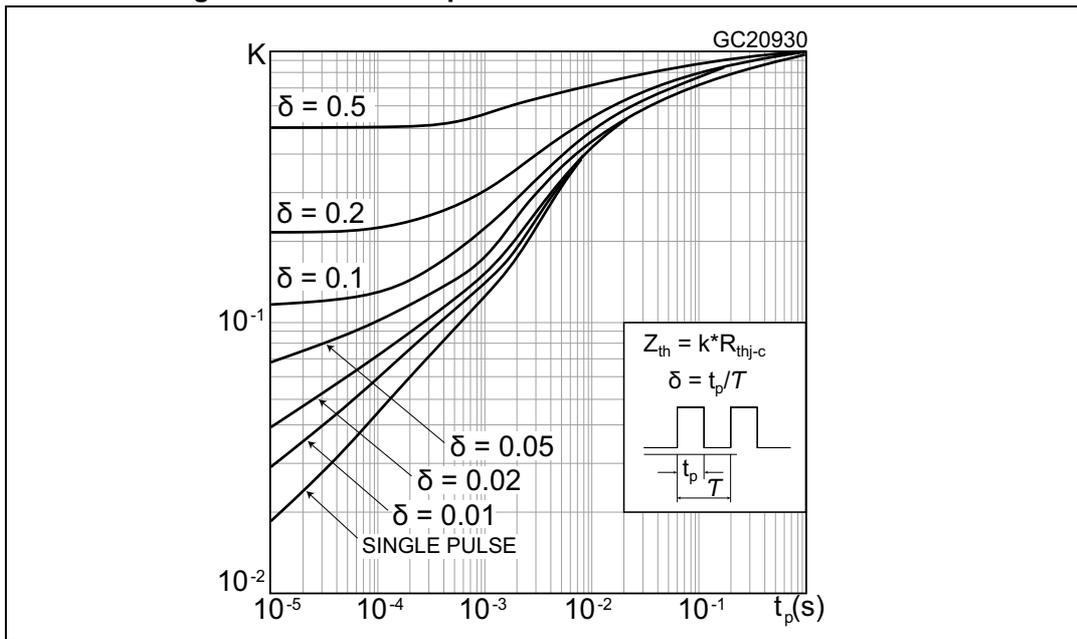


Figure 33. Thermal impedance for TO-220FP IGBT

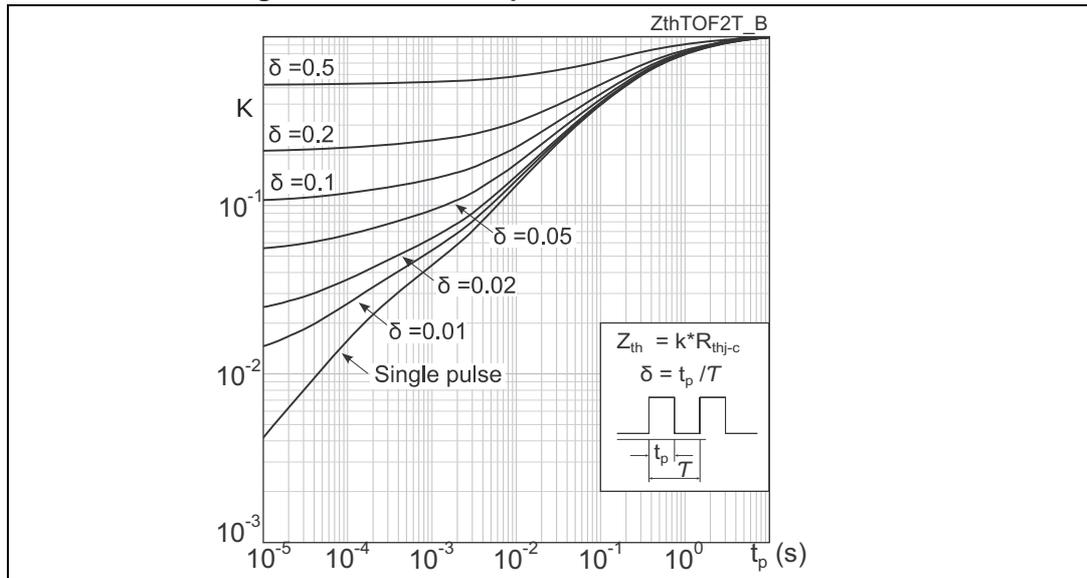
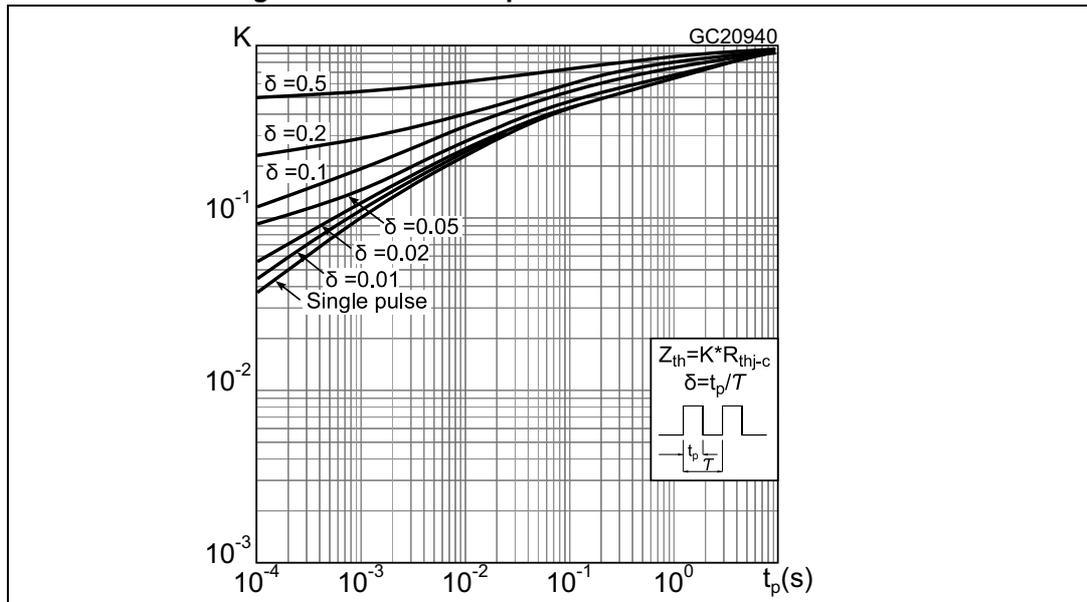


Figure 34. Thermal impedance for TO-220FP diode





## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 4.1 D<sup>2</sup>PAK package information

Figure 39. D<sup>2</sup>PAK (TO-263) type A package outline

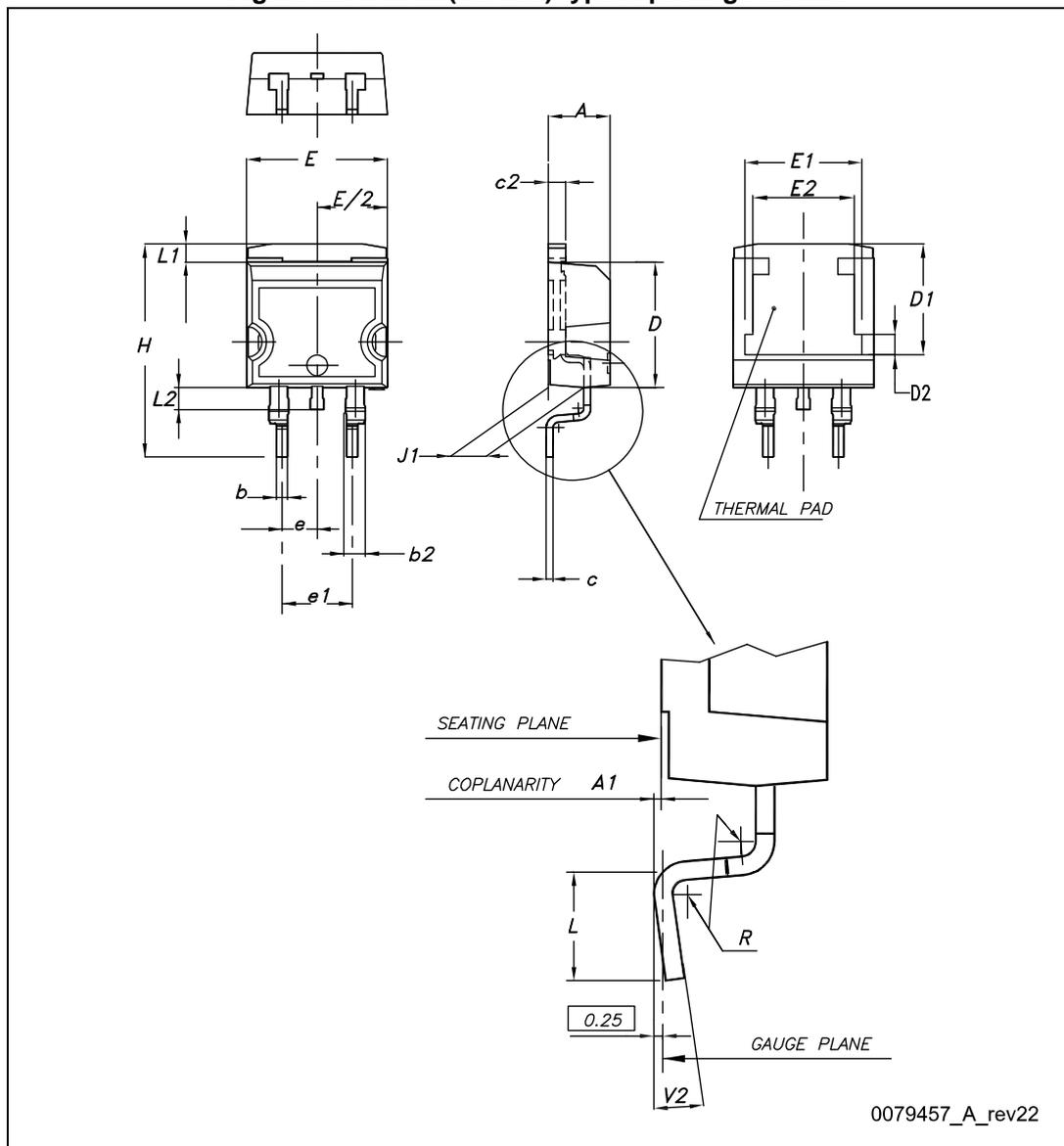
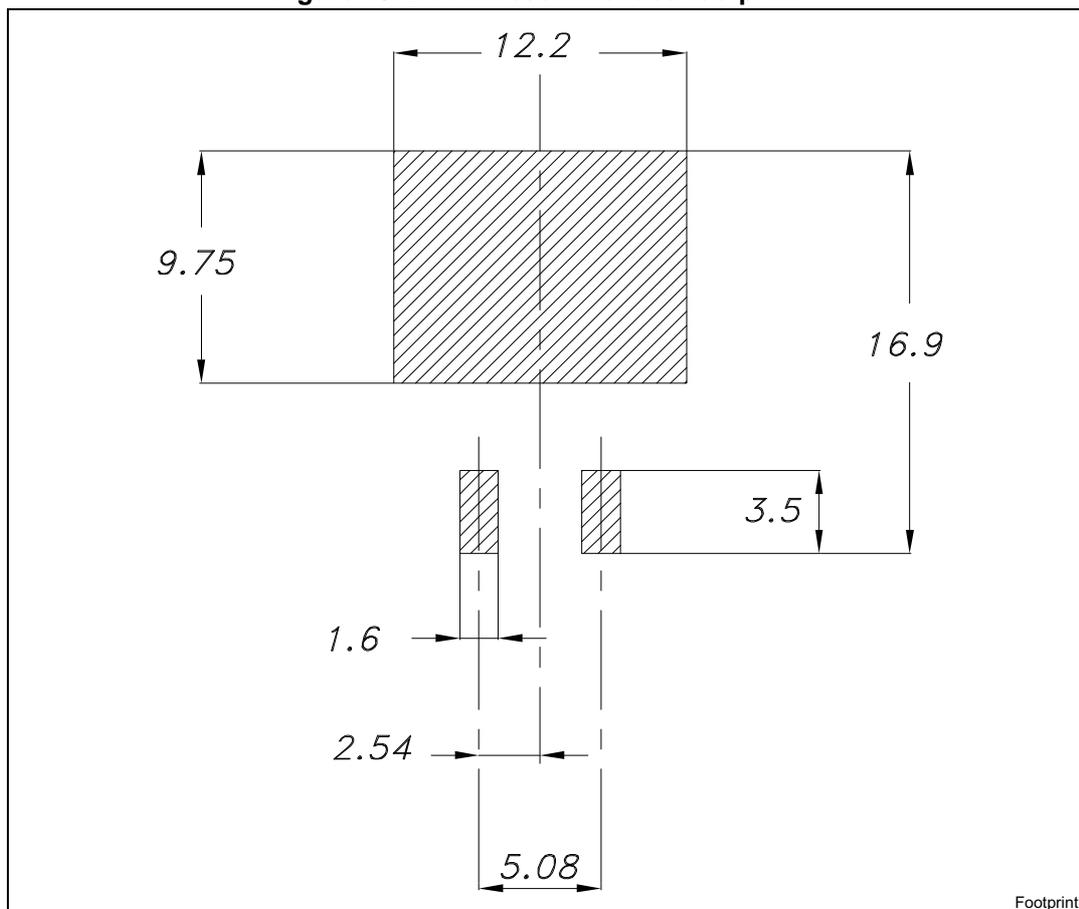


Table 9. D<sup>2</sup>PAK (TO-263) type A mechanical data

| Dim. | mm   |      |       |
|------|------|------|-------|
|      | Min. | Typ. | Max.  |
| A    | 4.40 |      | 4.60  |
| A1   | 0.03 |      | 0.23  |
| b    | 0.70 |      | 0.93  |
| b2   | 1.14 |      | 1.70  |
| c    | 0.45 |      | 0.60  |
| c2   | 1.23 |      | 1.36  |
| D    | 8.95 |      | 9.35  |
| D1   | 7.50 | 7.75 | 8.00  |
| D2   | 1.10 | 1.30 | 1.50  |
| E    | 10   |      | 10.40 |
| E1   | 8.50 | 8.70 | 8.90  |
| E2   | 6.85 | 7.05 | 7.25  |
| e    |      | 2.54 |       |
| e1   | 4.88 |      | 5.28  |
| H    | 15   |      | 15.85 |
| J1   | 2.49 |      | 2.69  |
| L    | 2.29 |      | 2.79  |
| L1   | 1.27 |      | 1.40  |
| L2   | 1.30 |      | 1.75  |
| R    |      | 0.4  |       |
| V2   | 0°   |      | 8°    |

Figure 40. D<sup>2</sup>PAK recommended footprint<sup>(a)</sup>



a. All dimension are in millimeters

### 4.2 D<sup>2</sup>PAK packing information

Figure 41. D<sup>2</sup>PAK tape outline

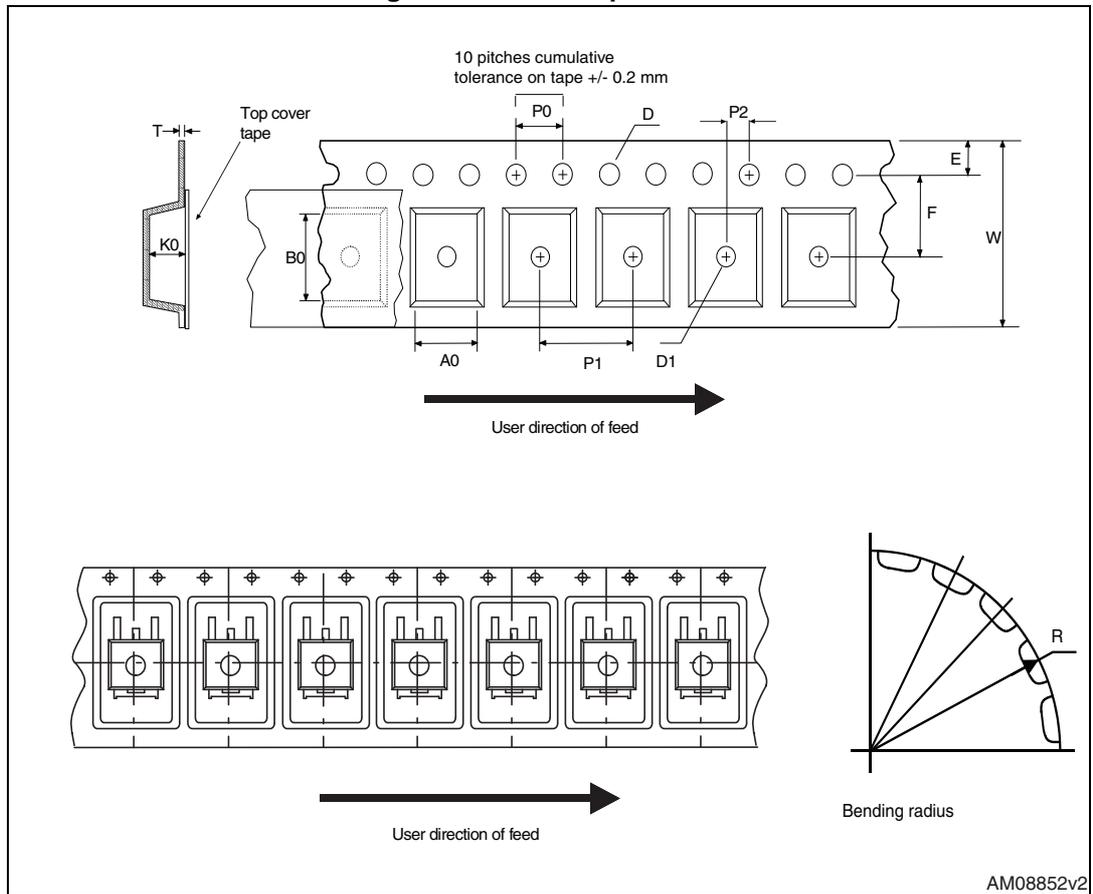
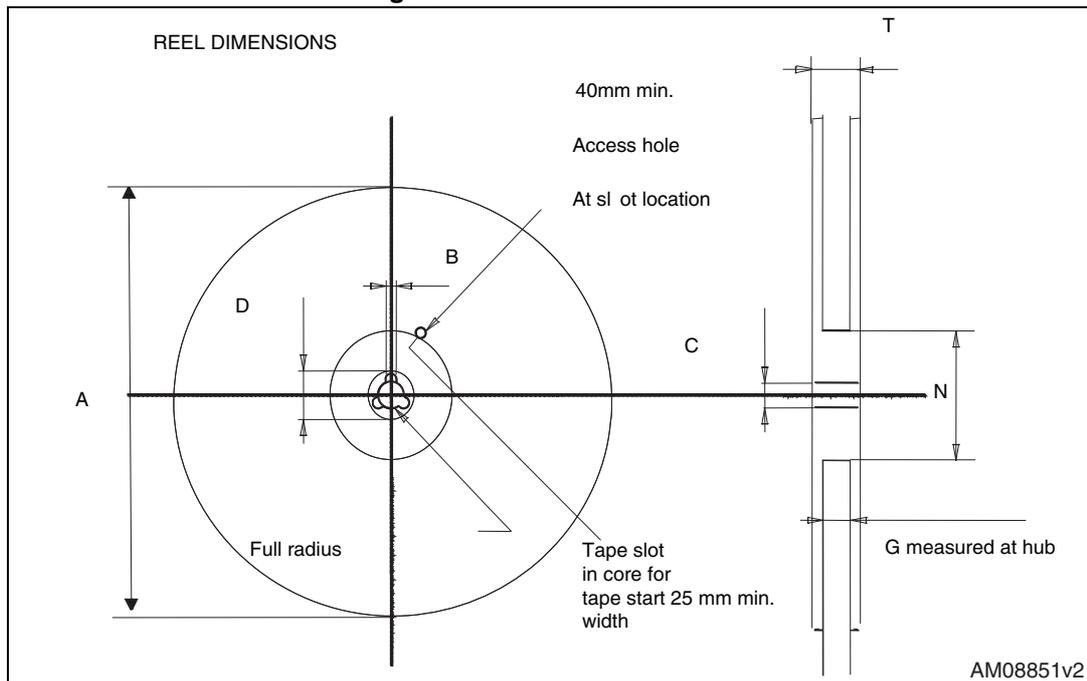


Figure 42. D<sup>2</sup>PAK reel outline



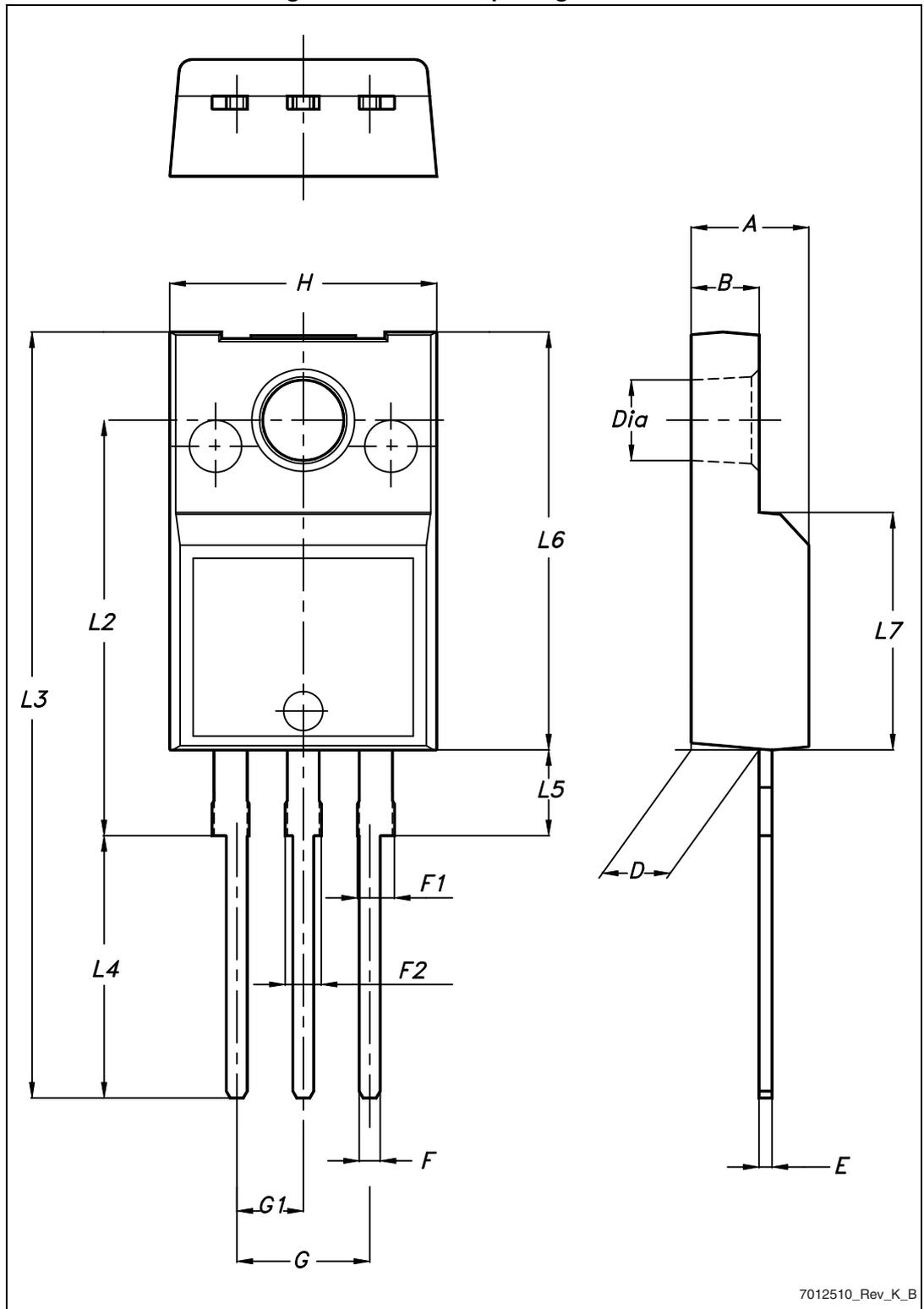
AM08851v2

Table 10. D<sup>2</sup>PAK tape and reel mechanical data

| Tape |      |      | Reel |          |      |
|------|------|------|------|----------|------|
| Dim. | mm   |      | Dim. | mm       |      |
|      | Min. | Max. |      | Min.     | Max. |
| A0   | 10.5 | 10.7 | A    |          | 330  |
| B0   | 15.7 | 15.9 | B    | 1.5      |      |
| D    | 1.5  | 1.6  | C    | 12.8     | 13.2 |
| D1   | 1.59 | 1.61 | D    | 20.2     |      |
| E    | 1.65 | 1.85 | G    | 24.4     | 26.4 |
| F    | 11.4 | 11.6 | N    | 100      |      |
| K0   | 4.8  | 5.0  | T    |          | 30.4 |
| P0   | 3.9  | 4.1  |      |          |      |
| P1   | 11.9 | 12.1 |      | Base qty | 1000 |
| P2   | 1.9  | 2.1  |      | Bulk qty | 1000 |
| R    | 50   |      |      |          |      |
| T    | 0.25 | 0.35 |      |          |      |
| W    | 23.7 | 24.3 |      |          |      |

### 4.3 TO-220FP package information

Figure 43. TO-220FP package outline



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Table 11. TO-220FP package mechanical data

| Dim. | mm   |      |      |
|------|------|------|------|
|      | Min. | Typ. | Max. |
| A    | 4.4  |      | 4.6  |
| B    | 2.5  |      | 2.7  |
| D    | 2.5  |      | 2.75 |
| E    | 0.45 |      | 0.7  |
| F    | 0.75 |      | 1    |
| F1   | 1.15 |      | 1.70 |
| F2   | 1.15 |      | 1.70 |
| G    | 4.95 |      | 5.2  |
| G1   | 2.4  |      | 2.7  |
| H    | 10   |      | 10.4 |
| L2   |      | 16   |      |
| L3   | 28.6 |      | 30.6 |
| L4   | 9.8  |      | 10.6 |
| L5   | 2.9  |      | 3.6  |
| L6   | 15.9 |      | 16.4 |
| L7   | 9    |      | 9.3  |
| Dia  | 3    |      | 3.2  |

### 4.4 TO-220 package information

Figure 44. TO-220 type A package outline

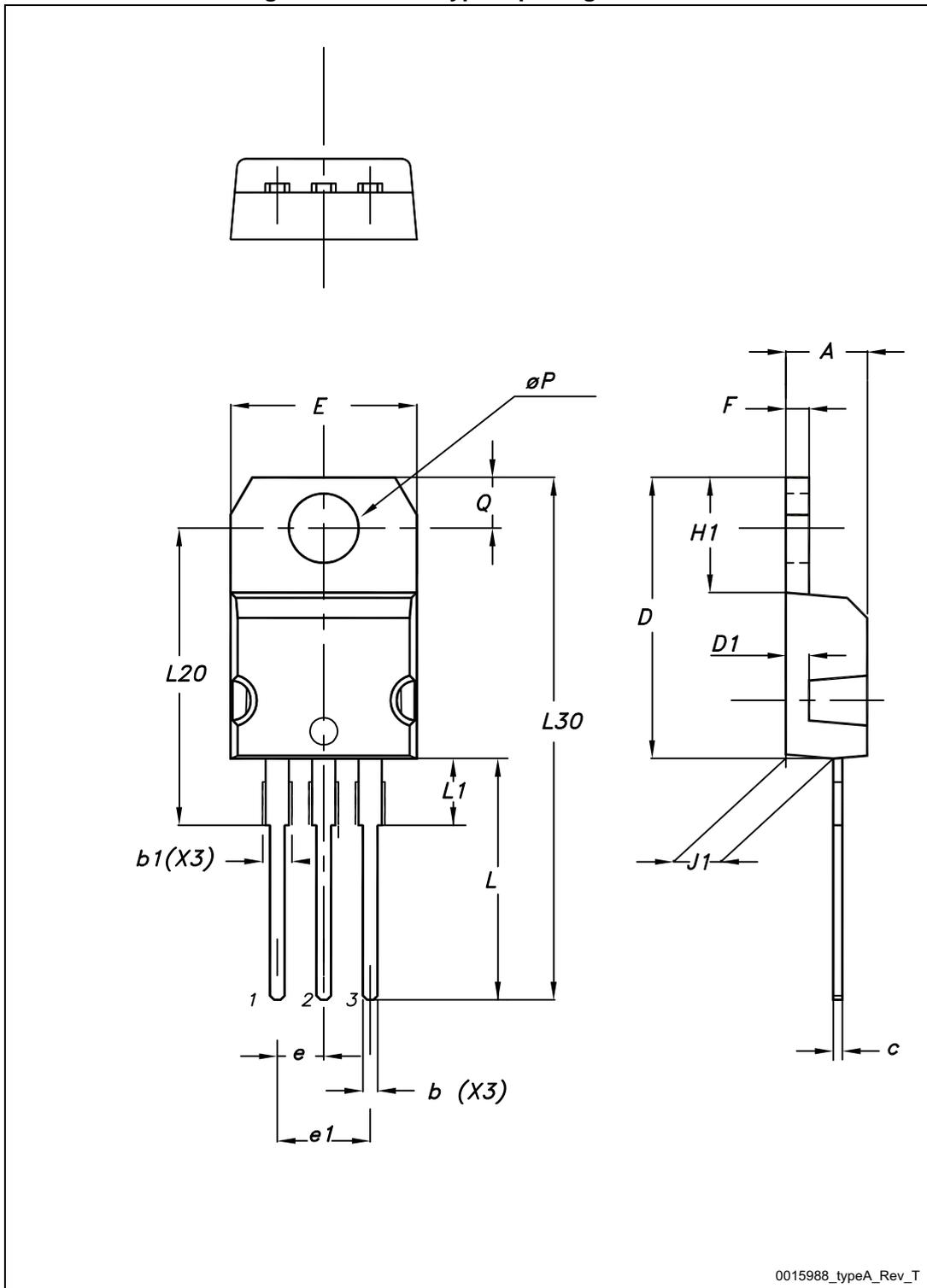


Table 12. TO-220 type A package mechanical data

| Dim. | mm    |       |       |
|------|-------|-------|-------|
|      | Min.  | Typ.  | Max.  |
| A    | 4.40  |       | 4.60  |
| b    | 0.61  |       | 0.88  |
| b1   | 1.14  |       | 1.70  |
| c    | 0.48  |       | 0.70  |
| D    | 15.25 |       | 15.75 |
| D1   |       | 1.27  |       |
| E    | 10    |       | 10.40 |
| e    | 2.40  |       | 2.70  |
| e1   | 4.95  |       | 5.15  |
| F    | 1.23  |       | 1.32  |
| H1   | 6.20  |       | 6.60  |
| J1   | 2.40  |       | 2.72  |
| L    | 13    |       | 14    |
| L1   | 3.50  |       | 3.93  |
| L20  |       | 16.40 |       |
| L30  |       | 28.90 |       |
| ØP   | 3.75  |       | 3.85  |
| Q    | 2.65  |       | 2.95  |

## 5 Revision history

Table 13. Document revision history

| Date        | Revision | Changes   |
|-------------|----------|---|
| 24-Feb-2015 | 1        | Initial release.  |
| 05-Jun-2015 | 2        | Text and formatting changes throughout document<br>In <a href="#">Section 1: Electrical ratings</a><br>- updated <a href="#">Table 3</a><br>In <a href="#">Section 2: Electrical characteristics</a><br>- updated <a href="#">Table 4</a> , <a href="#">Table 5</a> , <a href="#">Table 6</a> , <a href="#">Table 7</a> and <a href="#">Table 8</a><br>- added <a href="#">Section 2.1: Electrical characteristics (curves)</a> |

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